

INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT

Form PTO-1449 (Modified)  
(Use several sheets if necessary)

COMPLETE IF KNOWN

Application Number	10/642,370
Confirmation Number	2543
Filing Date	08/15/2003
First Named Inventor	Man Wang
Group Art Unit	2819
Examiner Name	
Attorney Docket No.	384848008US

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Examiner Initials*	Cite No.	U.S. Patent or Application		Name of Patentee or Inventor of Cited Document	Date of Publication or Filing Date of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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		4,543,594		Mohsen et al.	09/24/85	
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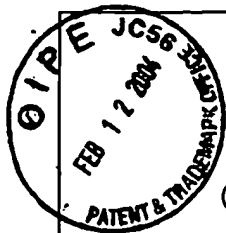
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*Paul J. Chong*

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*2/1/05*

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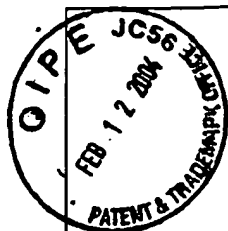
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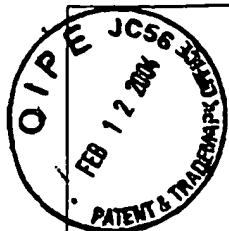
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JC	*	JP	61292295		Fujitsu Ltd.	12/23/86		

**OTHER PRIOR ART-NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume issue number(s), publisher, city and/or country where published.	T
JC	*	MIRANDA, ENRIQUE et al; Analytic Modeling of Leakage Current Through Multiple Breakdown Paths in SiO <sub>2</sub> Films; 39 <sup>th</sup> Annual International Reliability Physics Symposium; Orlando, FL 2001, pp. 369-379	

EXAMINER <i>Orin D. Chay</i>	DATE CONSIDERED <i>2/1/05</i>
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DC	*	LOMBARDO, S. et al; Softening of Breakdown in Ultra-Thin Gate Oxide nMOSFET's at Low Inversion Layer Density; 39 <sup>th</sup> Annual International Reliability Physics Symposium; Orlando, FL 2001, pp. 163-169	
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